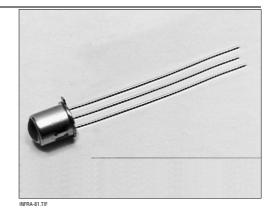
Optoschmitt Detector

FEATURES

- TO-46 metal can package
- 6° (nominal) acceptance angle
- High noise immunity output
- TTL/LSTTL/CMOS compatible
- Buffer (SD5600) or inverting (SD5610) logic available
- Mechanically and spectrally matched to SE3450/5450, SE3455/5455 and SE3470/5470 infrared emitting diodes



DESCRIPTION

The SD5600/5610 series is a family of single chip Optoschmitt IC detectors mounted in a TO-46 metal can package. The photodetector consists of a photodiode, amplifier, voltage regulator, Schmitt trigger and an NPN output transistor with 10 kΩ (nominal) pull-up resistor. Output rise and fall times are independent of the rate of change of incident light. Detector sensitivity has been internally temperature compensated. The TO-46 package is ideally suited for operation in hostile environments.

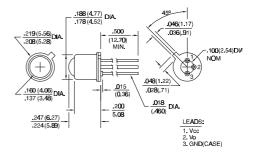
Device Polarity:

- Buffer Output is HI when incident light intensity is above the turn- on threshold level.
- Inverter Output is LO when incident light intensity is above the turn- on threshold level.

OUTLINE DIMENSIONS in inches (mm)

 Tolerance
 3 plc decimals
 ±0.005(0.12)

 2 plc decimals
 ±0.020(0.51)



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Optoschmitt Detector

ELECTRICAL CHARACTERISTICS (-40°C to +100°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Operating Supply Voltage	Vcc	4.5		16.0	V	T _A =25°C
Turn-on Threshold Irradiance (2) SD5600-001, SD5610-001	Eer(+)			2.50	mW/cm ²	Vcc=5 V T _A =25°C
Hysteresis ⁽³⁾	HYST	5		30	%	
Supply Current	lcc			12.0 15.0	mA	Ee=0 Or 3.0 mW/cm² Vcc=5 V Vcc=16 V
High Level Output Voltage SD5600 SD5610	Vон	2.4 2.4			V	V _{CC} =5 V, Iон=0 Ее=0 Ее=3.0 mW/cm²
Low Level Output Voltage SD5600 SD5610	Vol			0.4 0.4	V	V _{CC} =5 V, I _{OL} =12.8 mA Ee=0 Ee=3.0 mW/cm²
Internal Pull-Up Resistor	RINT	5.0	10.0	20.0	kΩ	
Operate Point Temperature Coefficient	Ортс		-0.76		%/°C	Emitter @ Constant Temperature
Output Rise Time	tr		60		ns	RL=390 Ω, CL=50 pF
Output Fall Time	t _f		15		ns	RL=390 Ω, CL=50 pF
Propagation Delay, Low-High, High-Low	t _{PLH} , t _{PHL}		5.0		μs	RL=390 Ω, CL=50 pF
Clock Frequency				100	kHz	RL=390 Ω, CL=50 pF

Notes 1. It is recommended that a bypass capacitor, 0.1 µF typical, be added between V_{CC} and GND near the device in order to stabilize The radiation source is an IRED with a peak wavelength of 935 nm.
 Hysteresis is defined as the difference between the operating and release threshold intensities, expressed as a percentage of the

operate threshold intensity.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

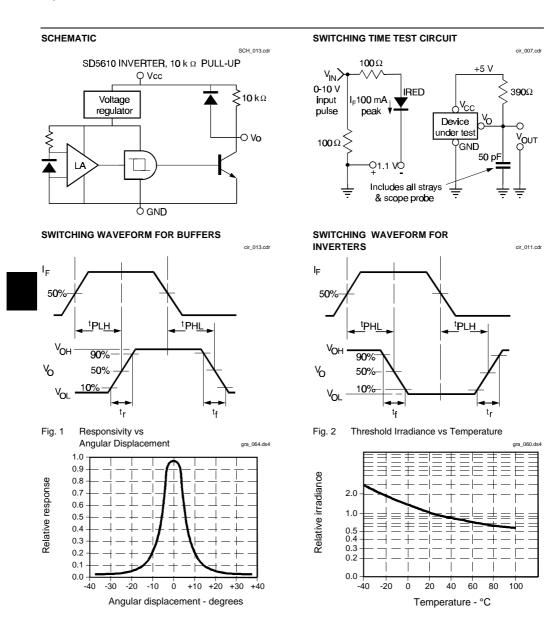
Supply Voltage Duration of Output Short to Vcc or Ground Output Current Operating Temperature Range Storage Temperature Range Soldering Temperature (10 sec) Notes 1. Derate linearly from 25°C to 7 V at 100°C.

SCHEMATIC SD5600 BUFFER, 10 k Ω PULL-UP Q Vcc 16 V (1) Voltage **≶10** kΩ 1.0 sec regulator 18 mA -40°C to 100°C ЮVо -55°C to 125°C 260°C LA 0 GND

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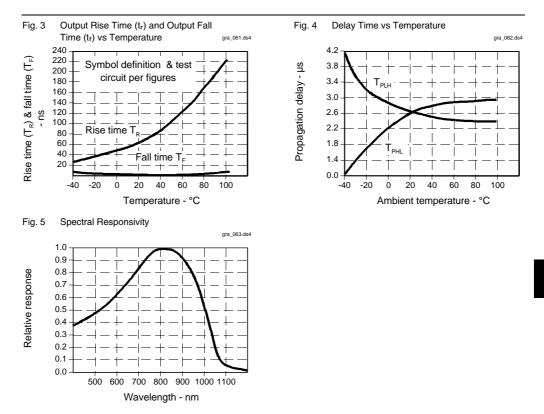
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All Performance Curves Show Typical Values

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